

High Power SPDT RF Switch

JSW2-63VHDRG+

RF Switch with internal driver
Single Supply Voltage, +2.3V to +5.5V

The Big Deal

- High power handling, 2.5W @2 GHz
- High IIP3, +75 dBm
- Low insertion loss, 0.4 dB
- Fast switching, 2 μ s
- Tiny Size, 2x2mm



CASE STYLE: MT2140

Product Overview

Mini-Circuits' JSW2-63VHDRG+ is a reflective symmetric MMIC SPDT switch with an internal CMOS driver designed for wideband operation from 5 to 6000 MHz. This model provides power handling up to 2.5W with low insertion loss, high dynamic range, and fast switching speed in a tiny 2x2mm 12-Lead MCLP package. JSW2-63VHDRG+ operates on a single positive supply voltage with low current consumption of just 120 μ A. Produced using a Silicon-on-Insulator process, it provides a high level of ESD protection and excellent repeatability.

The switching logic for this model sets the switch from COM to RF2 with control voltage in the low state and COM to RF1 with control voltage in the high state. Alternative model (JSW2-63VHDRP+) is also available with opposite switching logic for your convenience.

Key Features

| Feature | Advantages |
|---|---|
| Wideband, 5 to 6000 MHz | One model can be used in many applications, saving component count. Also ideal for wideband applications such as military and instrumentation. |
| High power and low loss <ul style="list-style-type: none">• 2.5W power handling @ 2 GHz• 0.4 dB insertion loss | Supports applications with a range of power requirements with excellent transmission of signal power from input to output. |
| High Isolation <ul style="list-style-type: none">• 68 dB at 100 MHz• 20 dB at 5000 MHz | High isolation significantly reduces leakage of power into OFF ports. |
| High linearity, <ul style="list-style-type: none">• +75 dBm IIP3• +115 dBm IIP2 | High linearity minimizes unwanted intermodulation products which are difficult or impossible to filter in multi-carrier environments, or in the presence of strong interfering signal from adjacent circuitry or received by antenna. |
| Built-in CMOS driver | Eliminates the need for an external driver, saving PCB space and cost. |
| Tiny size, 2 x 2mm QFN package | Tiny footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB. |



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50Ω 5 - 6000 MHz

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Single Supply Voltage, +2.3V to +5.5V

Product Features

- High Power, 2.5W at 2 GHz
- Low insertion loss, 0.4 dB typ. at 3 GHz
- High IIP3, 75 dBm typ. from 100-6000 MHz
- Low current consumption, 120 μA typ.
- Immune to latch up

Typical Applications

- Defense
- Communication Infrastructure
- Test and Measurements

General Description

JSW2-63VHDRG+ is a high power reflective symmetric SPDT switch with integral CMOS driver, operates with single positive supply voltage while consuming, 120 μA typical. It has been designed for wide band operation. It is packaged in a tiny 2x2 mm, 12-lead package and is rated MSL1 and passes 1KV for ESD (HBM).



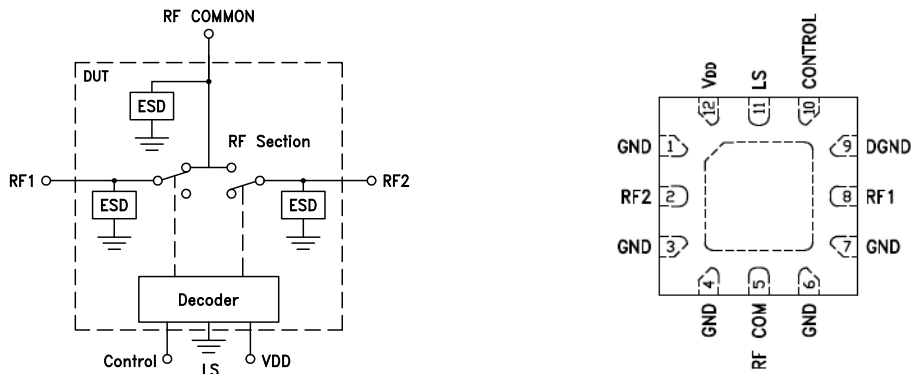
JSW2-63VHDRG+

CASE STYLE: MT2140

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Simplified Schematic and Pad Description



| Function | Pad Number | Description |
|----------|-------------------|----------------------|
| RF COM | 5 | RF common/ SUM port* |
| RF1 | 8 | RF OUT #1 / IN port* |
| RF2 | 2 | RF OUT #2 / IN port* |
| Control | 10 | CMOS Control IN |
| LS | 11 | Connect to ground |
| VDD | 12 | Supply |
| DGND | 9 | Digital Ground |
| GND | 1,3,4,6,7, Paddle | RF Ground |

*Must be held at 0Vdc. If required, add DC blocking capacitors to prevent DC on these ports.



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M161454
JSW2-63VHDRG+
RS/CP
170417
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RF Electrical Specifications¹, T_{AMB}=25°C, V_{DD}= +2.3 to +5.5V, 50 Ohms

| Parameter | Condition (MHz) | Min. | Typ. | Max. | Units |
|---|-----------------------------|------|------|------|-------|
| Frequency Range | | 5 | | 6000 | MHz |
| Insertion Loss ^{2,4} (ON STATE) | 5 - 100 | — | 0.23 | — | dB |
| | 100 - 1000 | — | 0.25 | 0.35 | |
| | 1000 - 2000 | — | 0.3 | 0.4 | |
| | 2000 - 3000 | — | 0.4 | 0.5 | |
| | 3000 - 4000 | — | 0.5 | 0.7 | |
| | 4000 - 5000 | — | 0.65 | 0.9 | |
| Isolation between Common Port and RF1/RF2 Ports | 5 - 100 | — | 68 | — | dB |
| | 100 - 1000 | 42 | 44 | — | |
| | 1000 - 2000 | 33 | 35 | — | |
| | 2000 - 3000 | 27 | 29 | — | |
| | 3000 - 4000 | 22 | 24 | — | |
| | 4000 - 5000 | 18 | 20 | — | |
| Isolation between RF1 and RF2 Ports | 5 - 100 | — | 61 | — | dB |
| | 100 - 1000 | 40 | 41 | — | |
| | 1000 - 2000 | 32 | 33 | — | |
| | 2000 - 3000 | 26 | 28 | — | |
| | 3000 - 4000 | 22 | 24 | — | |
| | 4000 - 5000 | 18 | 20 | — | |
| Return Loss ⁴ (ON STATE) | 5 - 100 | | 33 | | dB |
| | 100 - 1000 | | 28 | | |
| | 1000 - 2000 | | 21 | | |
| | 2000 - 3000 | | 20 | | |
| | 3000 - 4000 | | 18 | | |
| | 4000 - 5000 | | 16 | | |
| 2nd Harmonic ⁵ | +18 dBm Pin, 17-204 MHz | | -92 | | dBm |
| | +32 dBm Pout, 850/900 MHz | | -99 | | |
| | +32 dBm Pout, 1800/1900 MHz | | -101 | | |
| 3rd Harmonic ⁵ | +18 dBm Pin, 17-204 MHz | | -125 | | dBm |
| | +32 dBm Pout, 850/900 MHz | | -93 | | |
| | +32 dBm Pout, 1800/1900 MHz | | -87 | | |
| IIP2 | 5 | | 96 | | dBm |
| | 17 | | 105 | | |
| | 100 - 6000 | | 115 | | |
| IIP3 | 5 | | 75 | | dBm |
| | 17 | | 81 | | |
| | 5 - 6000 | | 75 | | |
| Input 0.1dB Compression point ³ | 5 - 100 | | 33 | | dBm |
| | 100 - 6000 | | 34 | | |
| θjA | | | 119 | | °C/W |

Notes:

1. Tested on Mini-Circuits' test board TB-949+ (see Characterization test circuit, Fig.1).
2. Insertion loss values are de-embedded from test board loss.
3. 0.1dB compression is a linearity measure and not meant for continuous operation. See Figure 2 for max operating power.
4. Insertion loss and return loss are improved by external matching.

DC Electrical Specifications

| Parameter | Min. | Typ. | Max. | Units |
|--------------------------|------|------|------|---------|
| Supply voltage, V_{DD} | 2.3 | 3.3 | 5.5 | V |
| Supply current | | 120 | 200 | μA |
| Control voltage Low | 0 | 0 | 0.5 | V |
| Control voltage High | 1.2 | 1.5 | 3.3 | V |

Switching Specifications

| Parameter | Condition | Min. | Typ. | Max. | Units |
|--------------------|--|------|------|------|------------|
| Switching time | 50% control to 90% RF or 10% RF | | 2 | 4 | μSec |
| Video feed-through | (control 0 to 1.5V, RF freq.=10 kHz, V_{DD} =3.3V) | | 26 | | mV_{P-P} |

Absolute Maximum Ratings⁵

| Parameter | Ratings |
|---------------------------|---|
| Operating temperature | -40°C to +85°C |
| Storage temperature | -65°C to 150°C |
| V_{DD} , Supply voltage | +2.3 to 5.5V |
| Voltage control | 0V Min., 3.3 Max. |
| RF Input power, CW | 5-100 MHz: 33 dBm 100-6000 MHz: 34 dBm |

5. Operation of this device above any of these conditions may cause permanent damage.

Truth Table (State of control voltage selects the desired switch)

| State of Control Voltage | RF common to | |
|--------------------------|--------------|-----|
| | RF1 | RF2 |
| High | ON | OFF |
| Low | OFF | ON |

ON- low insertion loss state OFF- Isolation State

Characterization / Application Circuits

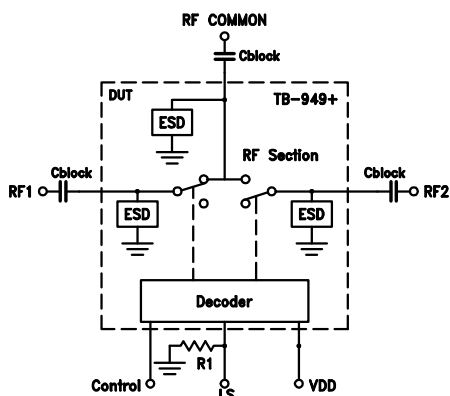


Figure 1. Block Diagram of test Circuit used for characterization R1=0 ohm (DUT & R1 soldered on Mini-Circuit's TB-949+)

Note: C_{block} is required only when DC is present on RF ports.

Power (Over-40 to 85°C) 50 Ohms

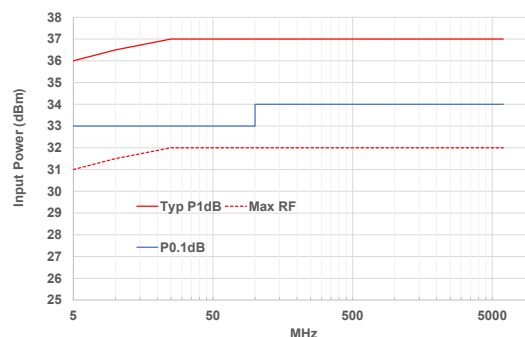
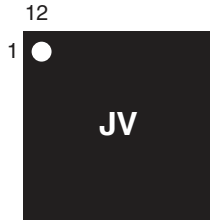


Figure 2. Max RF (operating), $P_{0.1dB}$ (Typ) and P_{1dB} (Typ) vs frequency.

Product Marking**Additional Detailed Technical Information**

additional information is available on our dash board. To access this information [click here](#)

| | |
|---|--|
| Performance Data | Data Table |
| | Swept Graphs |
| Case Style | MT2140 <i>Plastic package, exposed paddle</i> |
| Tape & Reel Standard quantities available on reel | F108 <i>7" reels with 20, 50, 100, 200, 500, 1000, 3000 devices</i> |
| Suggested Layout for PCB Design | PL-506 |
| Evaluation Board | TB-949+ |
| Environmental Ratings | ENV84 |

ESD Rating

Human Body Model (HBM): Class 1C (pass 1000V) in accordance with MIL-STD-883, Method 3015

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp